

Precision 16-Channel/Dual 8-Channel CMOS Analog Multiplexers

DESCRIPTION

The DG506B and DG507B are high performance analog multiplexers. Their ultra-low switch charge injection, low channel capacitance, and low leakage level allows them to achieve superior switching performance. The DG506B is a 16-channel single-ended analog multiplexer designed to connect one of sixteen inputs to a common output as determined by a 4-bit binary address (A0, A1, A2, A3). The DG507B is a dual 8-channel differential analog multiplexer designed to connect one of eight differential inputs to a common dual output as determined by its 3-bit binary address (A0, A1, A2). Break-before-make switching action protects against momentary crosstalk between adjacent channels.

An on channel conducts current equally well in both directions. In the off state each channel blocks voltages up to the power supply rails. An enable (EN) function allows the user to reset the multiplexer/demultiplexer to all switches off for stacking several devices. All control inputs, addresses (Ax) and enable (EN) are TTL compatible over the full specified operating temperature range.

The DG506B and DG507B are fabricated on an enhanced SG-II CMOS process that achieves improved performance on: reduced charge injection, lower device leakage, and minimized parasitic capacitance.

As the DG506, DG507 has a long history in the industry with many suppliers offering copies, and in some cases improved variations, with the best in class improvements, the Vishay Siliconix new version of the DG506B, DG507B are the superior alternatives to what is currently available.

Applications for the DG506B, DG507B include high speed and high precision data acquisition, audio signal switching and routing, ATE systems, and avionics. High performance and low power dissipation make them ideal for battery operated and remote instrumentation applications.

The DG506B and DG507B have the absolute maximum voltage rating extended to 44 V. Additionally, single supply operation is also allowed. An epitaxial layer prevents latch-up.

The DG506B and DG507B are both available in 28-lead SOIC and TSSOP package options with extended temperature range of - 40 °C to + 125 °C.

For more information, refer to Vishay Siliconix DG506B, DG507B evaluation board note.

FEATURES

- Operate with single or dual power supply
- V+ to V- analog signal swing range
- 44 V power supply maximum rating
- Extended operate temperature range:
- 40 °C to + 125 °C
- Low leakage typically < 3 pA
- Low charge injection - $Q_{INJ} = 1$ pC
- Low power - $I_{SUPPLY} = 5$ μ A
- TTL compatible logic
- > 250 mA latch up current per JESD78
- Available in SOIC28 and TSSOP28 packages
- Superior alternative to:
- ADG506A, DG506A, HI-506
- ADG507A, DG507A, HI-507
- **Compliant to RoHS directive 2002/95/EC**
- **Halogen-free according to IEC 61249-2-21 definition**



RoHS
COMPLIANT
HALOGEN
FREE

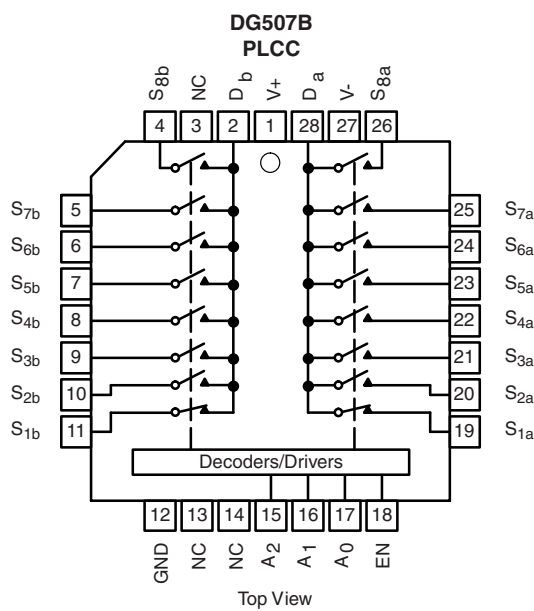
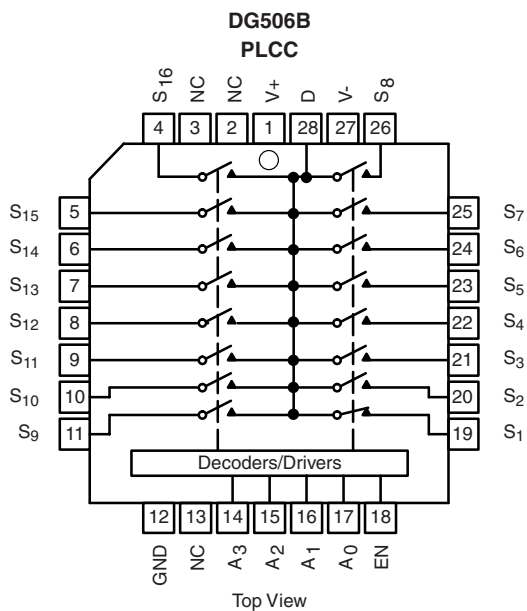
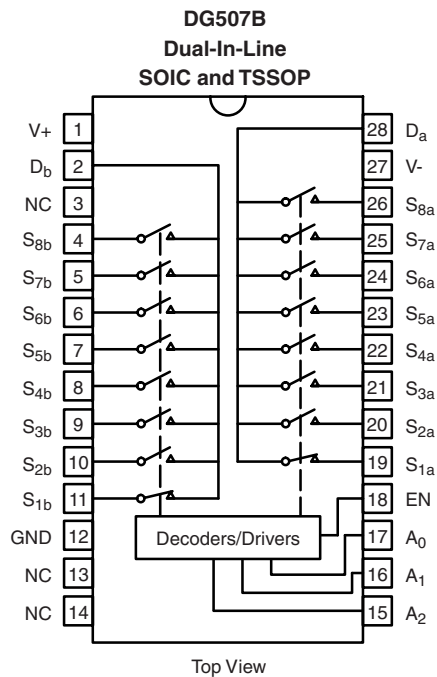
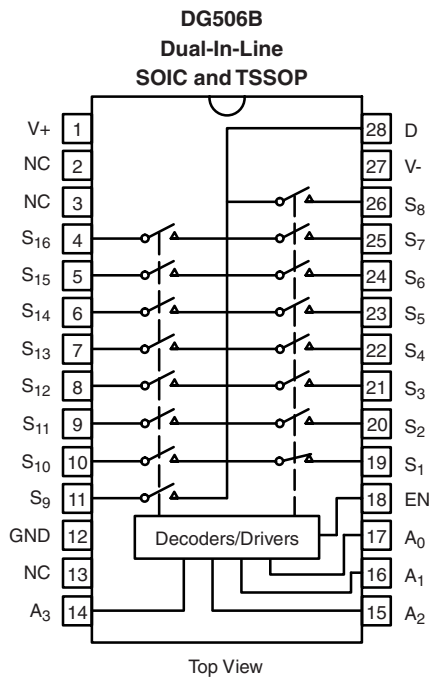
BENEFITS

- Reduced switching errors
- Reduced glitching
- Improved data throughput
- Reduced power consumption
- Increased ruggedness
- Wide supply ranges (± 5 V to ± 20 V)

APPLICATIONS

- Data acquisition systems
- Audio and video signal routing
- ATE systems
- Medical instrumentation

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



**TRUTH TABLE DG506B**

A ₃	A ₂	A ₁	A ₀	EN	On Switch
X	X	X	X	0	None
0	0	0	0	1	1
0	0	0	1	1	2
0	0	1	0	1	3
0	0	1	1	1	4
0	1	0	0	1	5
0	1	0	1	1	6
0	1	1	0	1	7
1	1	1	1	1	8
1	0	0	0	1	9
1	0	0	1	1	10
1	0	1	0	1	11
1	0	1	1	1	12
1	1	0	0	1	13
1	1	0	1	1	14
1	1	1	0	1	15
1	1	1	1	1	16

TRUTH TABLE DG507B

A ₂	A ₁	A ₀	EN	On Switch
X	X	X	0	None
0	0	0	1	1
0	0	0	1	2
0	1	1	1	3
0	1	1	1	4
1	0	0	1	5
1	0	0	1	6
1	1	1	1	7
1	1	1	1	8

Logic "0" = $V_{IL} \leq 0.8 \text{ V}$ Logic "1" = $V_{IH} \geq 2.4 \text{ V}$

X = Do not care

ORDERING INFORMATION DG506B

Temp. Range	Package	Part Number
- 40 °C to 125 °C	28-Pin SOIC	DG506BEW-T1-GE3
	28-Pin TSSOP	DG506BEQ-T1-GE3
	28-Pin PLCC	DG506BEN-T1-GE3

ORDERING INFORMATION DG507B

Temp. Range	Package	Part Number
- 40 °C to 125 °C	28-Pin SOIC	DG507BEW-T1-GE3
	28-Pin TSSOP	DG507BEQ-T1-GE3
	28-Pin PLCC	DG507BEN-T1-GE3

ABSOLUTE MAXIMUM RATINGS

Parameter		Limit	Unit
Voltages Referenced to V-	V+	44	V
	GND	25	
Digital Inputs ^a , V _S , V _D		(V-) - 2 to (V+) + 2 or 20 mA, whichever occurs first	
Current (Any terminal)		30	mA
Peak Current, S or D (Pulsed at 1 ms, 10 % duty cycle max.)		100	
Storage Temperature	(EW, EQ, EN suffix)	- 65 to 150	°C
Power Dissipation (Packages) ^b	28-Pin Wide Body SOIC ^c	840	mW
	28-Pin TSSOP ^d	817	
	28-Pin PLCC ^e	1693	
Thermal Resistance (θ_{JA}) ^b	28-Pin Wide Body SOIC ^c	95.3	°C/W
	28-Pin TSSOP ^d	97.9	
	28-Pin PLCC ^e	47.3	

Notes:

a. Signals on S_X, D_X or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads soldered or welded to PC board.

c. Derate 10.5 mW/°C above 70 °C.

d. Derate 10.2 mW/°C above 70 °C.

e. Derate 21.2 mW/°C above 70 °C.

SPECIFICATIONS											
Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 15 V, V- = - 15 V (± 10 %) V _{AX} , V _{EN} = 2.4 V, 0.8 V ^a		Temp. ^b	Typ. ^c	A Suffix - 40 °C to 125 °C		D Suffix - 40 °C to 85 °C		Unit	
						Min. ^d	Max. ^d	Min. ^d	Max. ^d		
Analog Switch											
Analog Signal Range ^e	V _{ANALOG}			Full		- 15	15	- 15	15	V	
Drain-Source On-Resistance	R _{DS(on)}	V _D = ± 10 V, I _S = - 1 mA		Room	170		300		300	Ω	
				Full			400		400		
R _{DS(on)} Matching	ΔR _{DS(on)}	V _D = ± 10 V		Room	10						
Source Off Leakage Current	I _{S(off)}	V _D = ± 10 V V _S = ∓ 10 V V _{EN} = 0 V		Room	0.005	- 1	1	- 1	1	nA	
				Full		- 50	50	- 50	50		
Drain Off Leakage Current	I _{D(off)}			DG506B	Room	0.005	- 1	1	- 1		1
					Full		- 100	100	- 100		100
				DG507B	Room	0.005	- 1	1	- 1		1
					Full		- 50	50	- 50		50
Drain On Leakage Current	I _{D(on)}	V _S = V _D = ∓ 10 V sequence each switch on	DG506B	Room	0.005	- 1	1	- 1	1		
				Full		- 100	100	- 100	100		
			DG507B	Room	0.005	- 1	1	- 1	1		
				Full		- 50	50	- 50	50		
Digital Control											
Logic High Input Voltage	V _{INH}			Full		2.4		2.4		V	
Logic Low Input Voltage	V _{INL}			Full			0.8		0.8		
Logic High Input Current	I _{IH}	V _{AX} , V _{EN} = 2.4 V		Full		- 1	1	- 1	1	μA	
Logic Low Input Current	I _{IL}	V _{AX} , V _{EN} = 0.8 V		Full		- 1	1	- 1	1		
Logic Input Capacitance ^e	C _{in}	f = 1 MHz		Room	5					pF	
Dynamic Characteristics											
Transition Time	t _{TRANS}	VS ₁ = + 10 V/- 10 V, VS ₁₆ = - 10 V/+ 10 V, R _L = 1 MΩ, C _L = 35 pF see figure 2		Room	190		300		300	ns	
				Full			360		360		
Break-Before-Make Interval	t _{OPEN}	VS ₁ = VS ₁₆ = 5.0 V, C _L = 35 pF, R _L = 1 kΩ, see figure 4		Room	84	30		30			
				Full		10		10			
Enable Turn-On Time	t _{ON(EN)}	VS ₁ = 5 V, VS ₂ to VS ₁₆ = 0 V, R _L = 1 kΩ, C _L = 35 pF see figure 3		Room	151		250		250		
				Full			310		310		
Enable Turn-Off Time	t _{OFF(EN)}			Room	53		200		200		
				Full			220		220		
Charge Injection ^e	Q _{INJ}	C _L = 1 nF, R _{GEN} = 0 Ω, V _{GEN} = 0 V		Full	1					pC	
Off Isolation ^e	OIRR	C _L = 5 pF, R _L = 50 Ω, f = 1 MHz	DG506B	Room	- 85					dB	
			DG507B		- 84						
Crosstalk ^e	XTALK	C _L = 5 pF, R _L = 50 Ω, f = 1 MHz	DG506B	Room	- 85						
			DG507B		- 84						
- 3 dB Bandwidth ^e	BW	R _L = 50 Ω	DG506B	Room	114					MHz	
			DG507B		217						
Total Harmonic Distortion ^e	THD	R _L = 10 kΩ, 5 V _{rms}		Room	0.04					%	
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz		Room	3					pF	
Drain Off Capacitance ^e	C _{D(off)}			DG506B	Room	31					
				DG507B	Room	17					
Drain On Capacitance ^e	C _{D(on)}			DG506B	Room	38					
				DG507B	Room	24					
Power Supply											
Positive Supply Current	I+	V _{AX} , V _{EN} = 0 V or 5 V		Room	0.005		0.1		0.1	mA	
				Full			0.1		0.1		
Negative Supply Current	I-			Full		- 1		- 1			μA



SPECIFICATIONS Single Supply 12 V										
Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 12 V, V- = 0 V (± 10 %) V _{AX} , V _{EN} = 2.4 V, 0.8 V ^a		Temp. ^b	Typ. ^c	A Suffix - 40 °C to 125 °C		D Suffix - 40 °C to 85 °C		Unit
		Min. ^d	Max. ^d			Min. ^d	Max. ^d			
Analog Switch										
Analog Signal Range ^e	V _{ANALOG}			Full		0	12	0	12	V
On-Resistance	R _{DS(on)}	V _D = 10 V/0 V, I _S = 1 mA		Room	270		450		450	Ω
				Full			650		650	
R _{DS(on)} Matching	ΔR _{DS(on)}			Room	10					
Switch Off Leakage Current	I _{S(off)}	V+ = 12 V, V- = 0 V V _D = 0 V/10 V, V _S = 10 V/0 V		Room	0.005	- 1	1	- 1	1	nA
						Full		- 50	- 50	
	I _{D(off)}			Room	0.005	- 1	1	- 1	1	
						Full		- 100	100	
	I _{D(off)}			Room	0.005	- 1	1	- 1	1	
						Full		- 50	50	
Channel On Leakage Current	I _{D(on)}	V+ = 12 V, V- = 0 V V _S = V _D = 0 V/10 V		Room	0.005	- 1	1	- 1	1	
						Full		- 100	100	- 100
				Room	0.005	- 1	1	- 1	1	
						Full		- 50	50	- 50
Digital Control										
Logic High Input Voltage	V _{INH}			Full		2.4		2.4		V
Logic Low Input Voltage	V _{INL}			Full			0.8		0.8	
Logic High Input Current	I _{IH}	V _{AX} , V _{EN} = 2.4 V		Full		- 1	1	- 1	1	μA
Logic Low Input Current	I _{IL}	V _{AX} , V _{EN} = 0.8 V		Full		- 1	1	- 1	1	
Logic Input Capacitance ^e	C _{in}	f = 1 MHz		Room	5					pF
Dynamic Characteristics										
Transition Time	t _{TRANS}	VS ₁ = 10 V/0 V, VS ₁₆ = 0 V/10 V, R _L = 1 MΩ, C _L = 35 pF, see figure 2		Room	228		380		380	ns
				Full			450		450	
Break-Before-Make Interval	t _{OPEN}	VS ₁ = VS ₁₆ = 5 V, C _L = 35 pF, R _L = 1 kΩ, see figure 4		Room	115	40		40		
				Full		10		10		
Enable Turn-On Time	t _{ON(EN)}	VS ₁ = 5 V, VS ₂ to VS ₁₆ = 0 V, R _L = 1 kΩ, C _L = 35 pF see figure 3		Room	197		300		300	
				Full			420		420	
Enable Turn-Off Time	t _{OFF(EN)}			Room	46		200		200	
				Full			220		220	
Charge Injection ^e	Q _{INJ}	C _L = 1 nF, R _{GEN} = 0 Ω, V _{GEN} = 0 V		Full	4					pC
Off Isolation ^e	OIRR	C _L = 5 pF, R _L = 50 Ω f = 1 MHz		Room	- 86					dB
					- 84					
Crosstalk ^e	X _{TALK}	C _L = 5 pF, R _L = 50 Ω f = 1 MHz		Room	- 85					
					- 84					
- 3 dB Bandwidth ^e	BW	R _L = 50 Ω		Room	104					MHz
					191					
Total Harmonic Distortion ^e	THD	R _L = 10 kΩ, 5 V _{RMS} , f = 20 Hz to 20 kHz		Room	0.23					%

SPECIFICATIONS Single Supply 12 V											
Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 12 V, V- = 0 V (± 10 %) VAX, VEN = 2.4 V, 0.8 V ^a		Temp. ^b	Typ. ^c	A Suffix - 40 °C to 125 °C		D Suffix - 40 °C to 85 °C		Unit	
						Min. ^d	Max. ^d	Min. ^d	Max. ^d		
Dynamic Characteristics											
Source Off Capacitance ^e	CS(off)	f = 1 MHz		Room	4					pF	
Drain Off Capacitance ^e	CD(off)				DG506B	37					
					DG507B	20					
Channel On Capacitance ^e	CD(on)				DG506B	43					
					DG507B	26					
Power Supply											
Power Supply Current	I+	VAX, VEN = 0 V, or 5 V		Room	0.005		0.1		0.1	mA	
				Full			0.1		0.1		

Notes:

a. V_{AX} , V_{EN} = input voltage perform proper function.

b. Room = 25 °C, Full = as determined by the operating temperature suffix.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.

e. Guaranteed by design, not subject to production test.

f. $\Delta R_{DS(on)} = R_{DS(on)} \text{ max.} - R_{DS(on)} \text{ min.}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

SCHEMATIC DIAGRAM Typical Channel

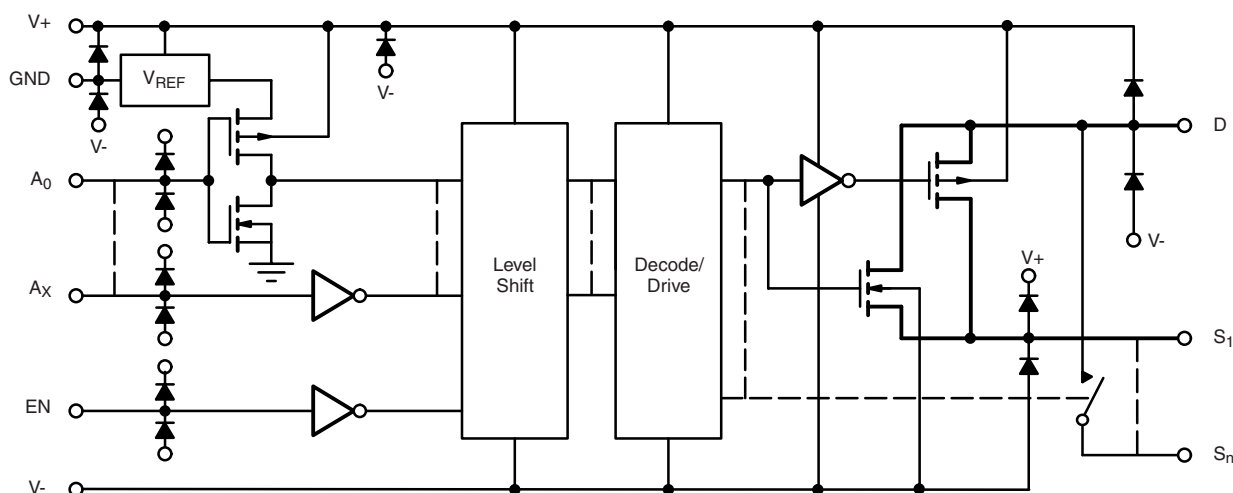
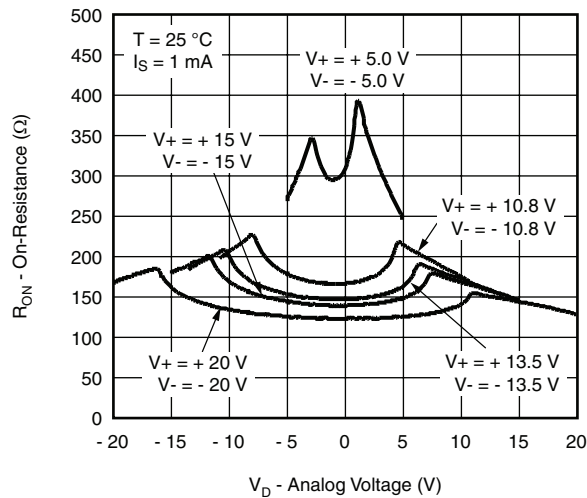
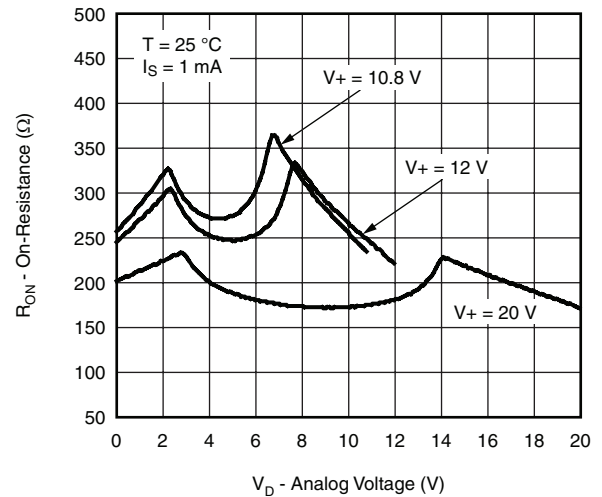
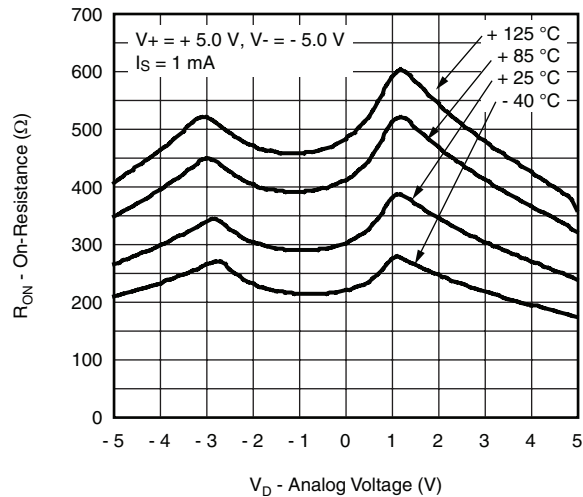
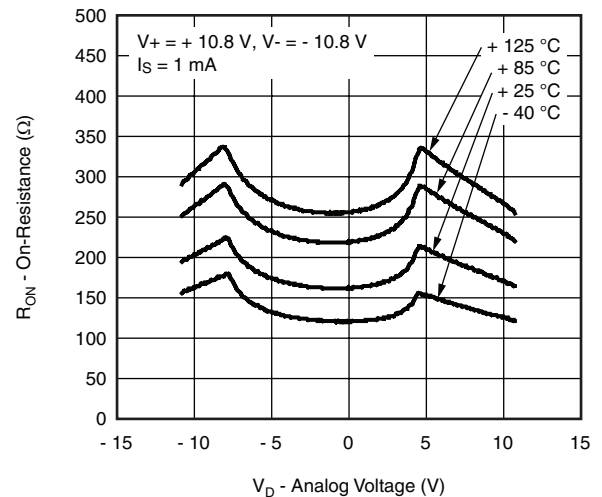
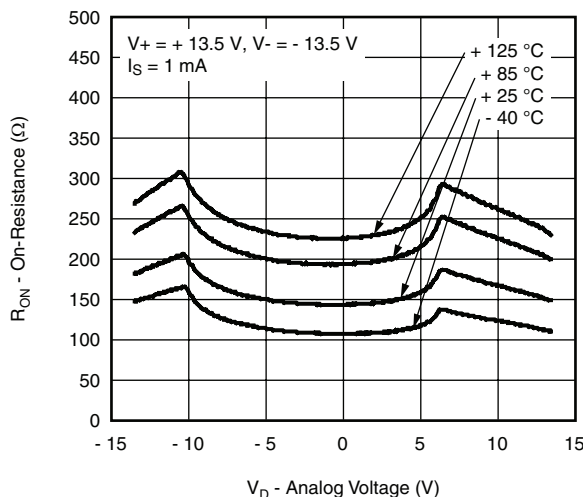
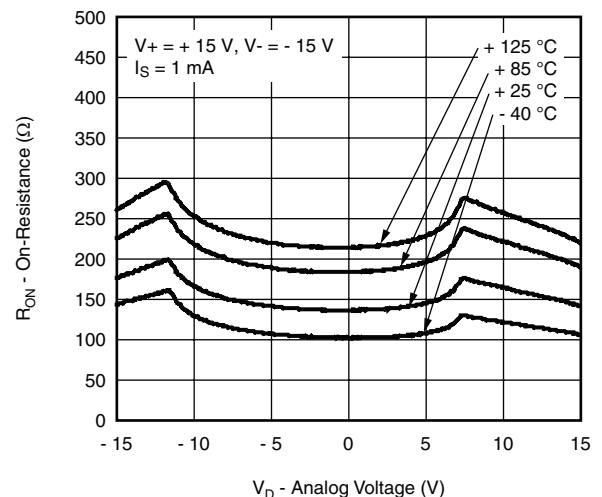
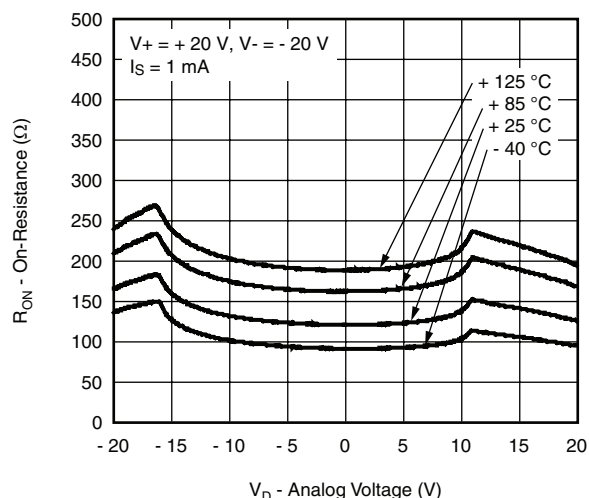


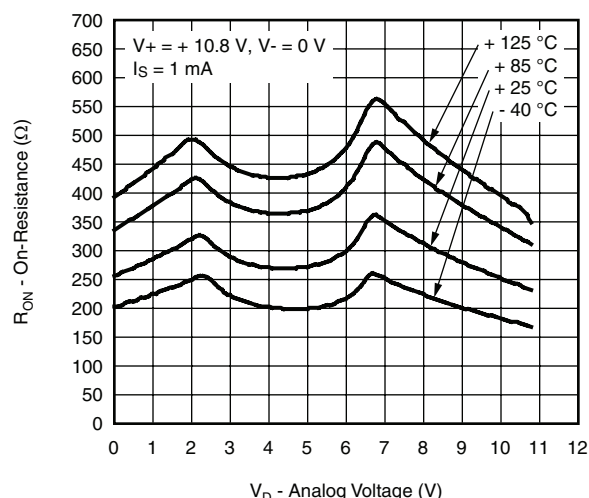
Figure 1.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

On-Resistance vs. V_D and Dual Supply Voltage

On-Resistance vs. V_D and Single Supply Voltage

On-Resistance vs. Analog Voltage and Temperature

On-Resistance vs. Analog Voltage and Temperature

On-Resistance vs. Analog Voltage and Temperature

On-Resistance vs. Analog Voltage and Temperature

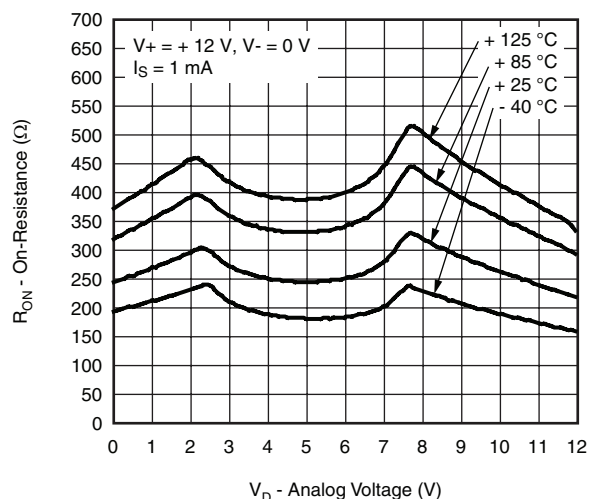
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



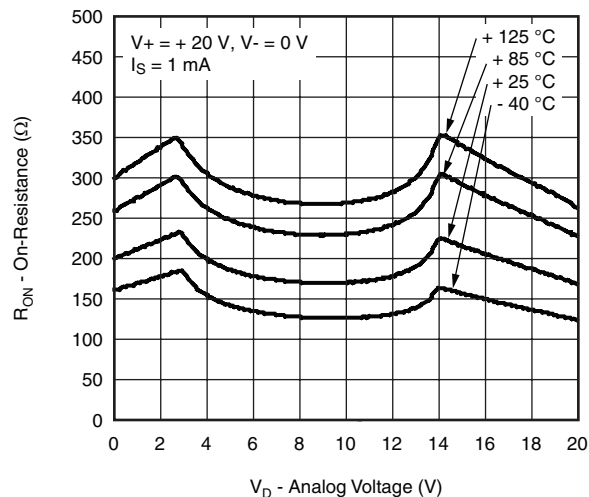
On-Resistance vs. Analog Voltage and Temperature



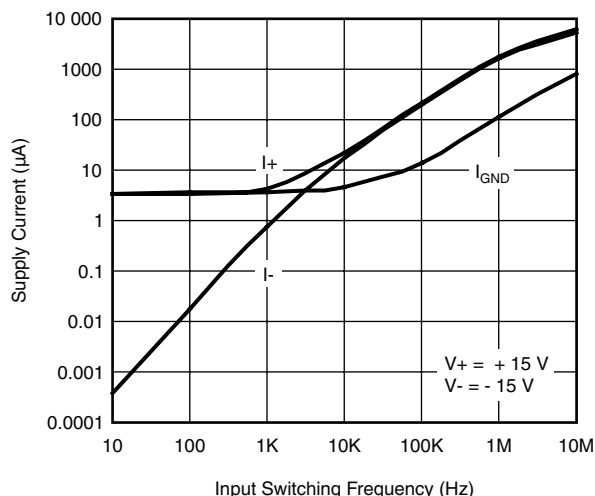
On-Resistance vs. Analog Voltage and Temperature



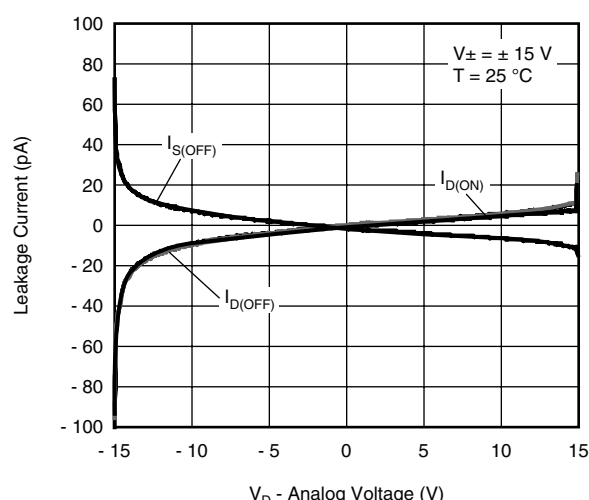
On-Resistance vs. Analog Voltage and Temperature



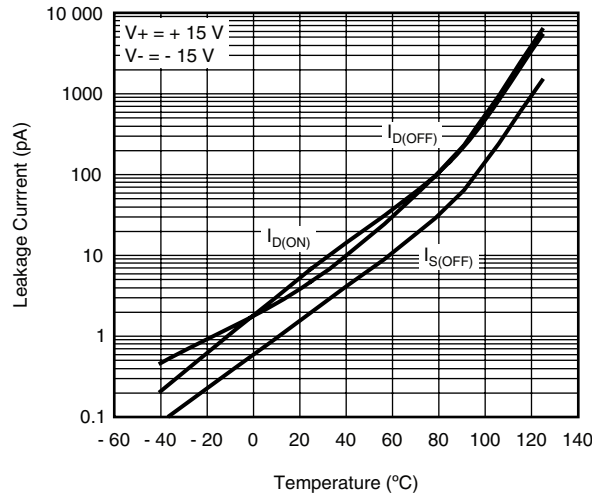
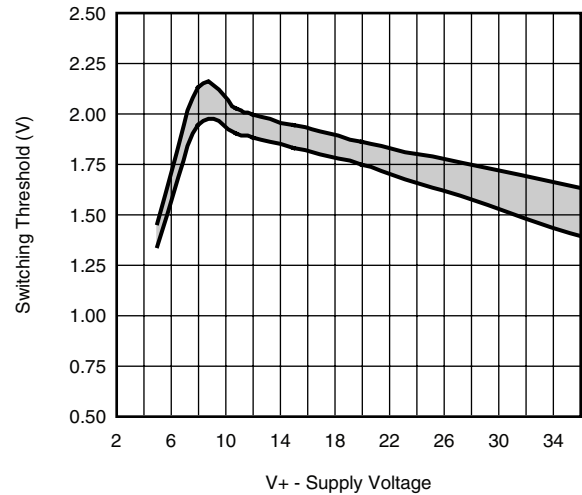
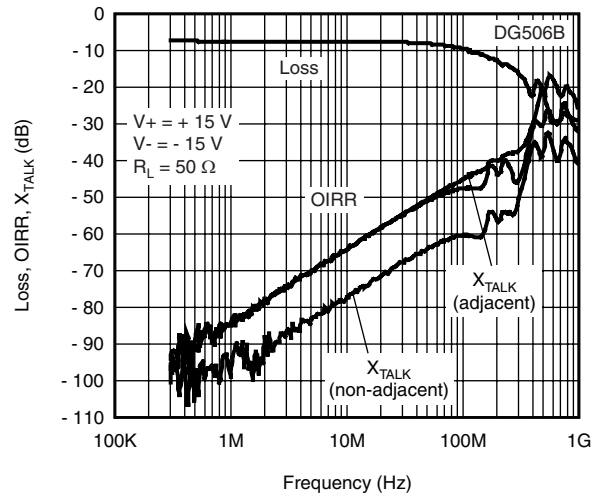
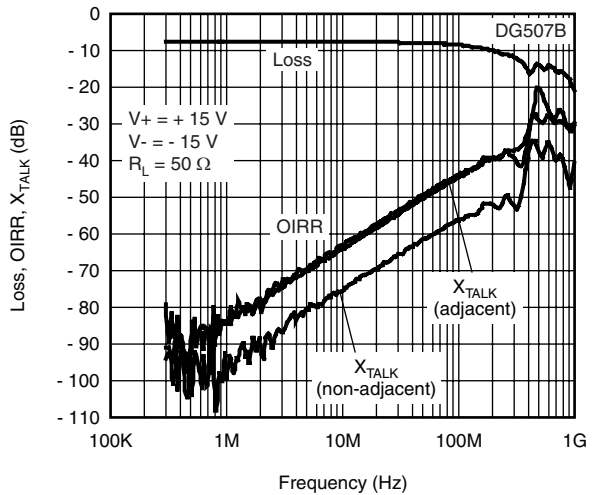
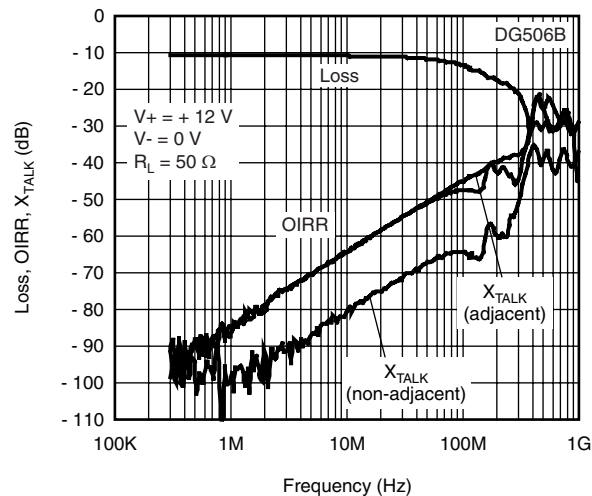
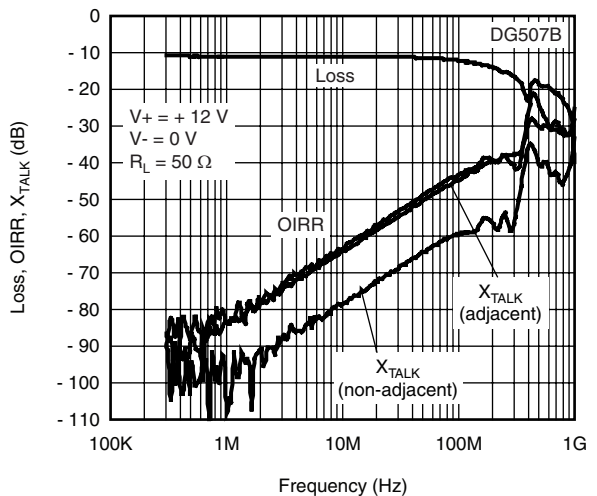
On-Resistance vs. Analog Voltage and Temperature



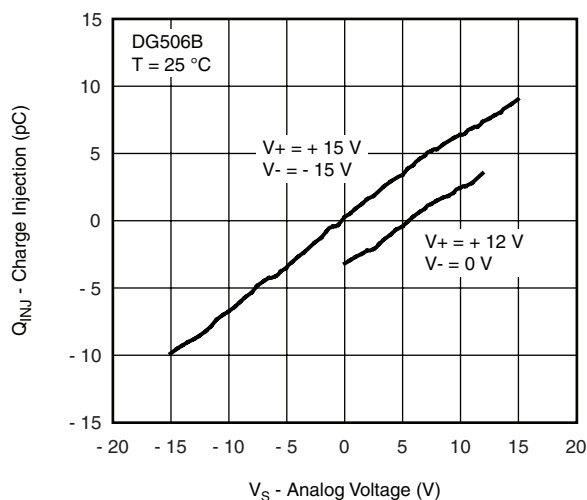
Supply Current vs. Input Switching Frequency



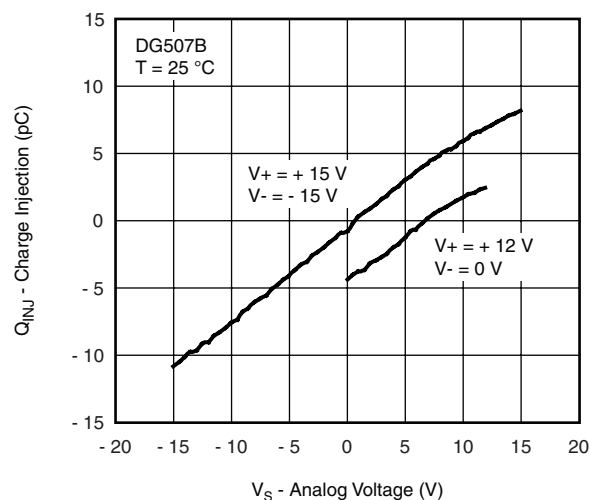
Leakage Current vs. Analog Voltage

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

Leakage Current vs. Temperature

Switching Threshold vs. Single Supply V

Insertion Loss, Off-Isolation, Crosstalk vs. Frequency

Insertion Loss, Off-Isolation, Crosstalk vs. Frequency

Insertion Loss, Off-Isolation, Crosstalk vs. Frequency

Insertion Loss, Off-Isolation, Crosstalk vs. Frequency

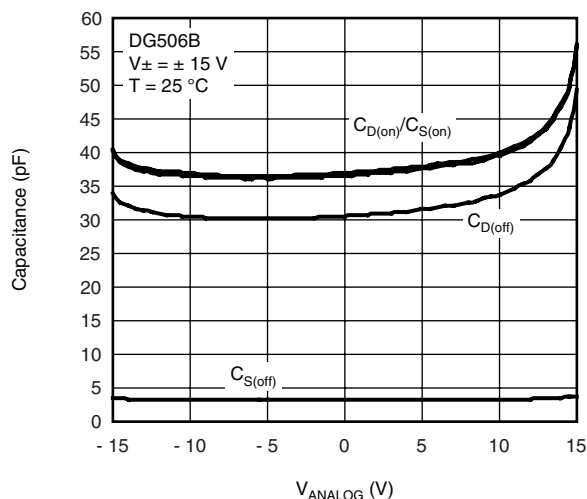
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



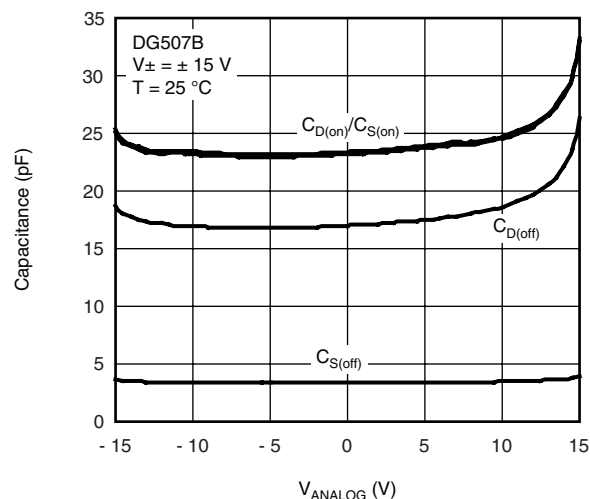
Charge Injection vs. Analog Voltage



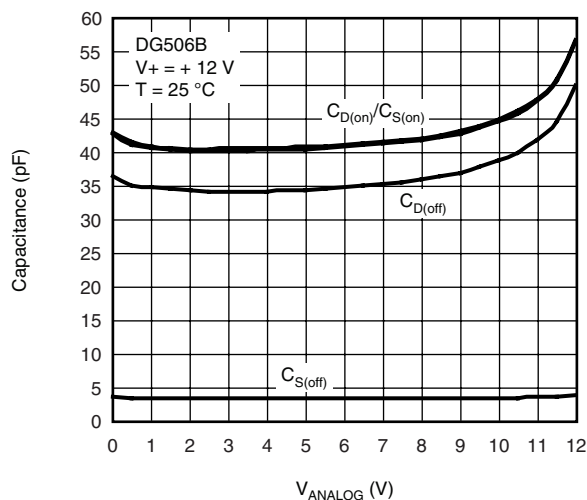
Charge Injection vs. Analog Voltage



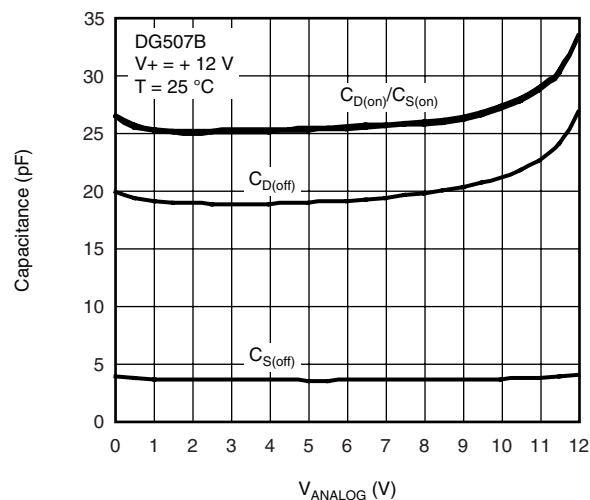
Capacitance vs. V_{ANALOG}



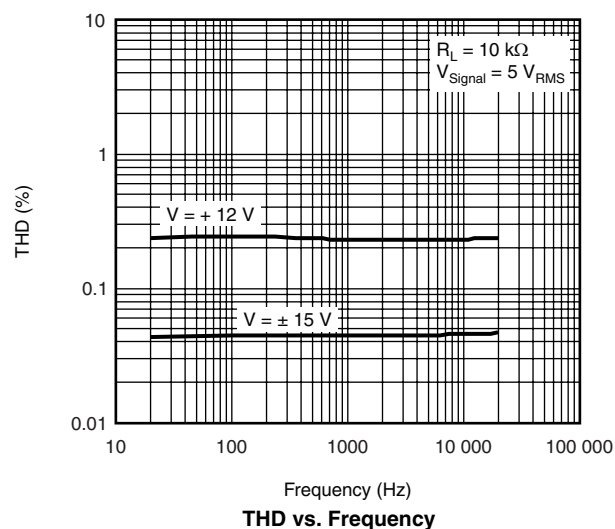
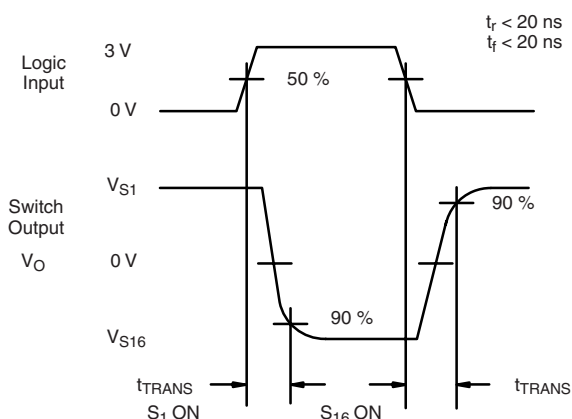
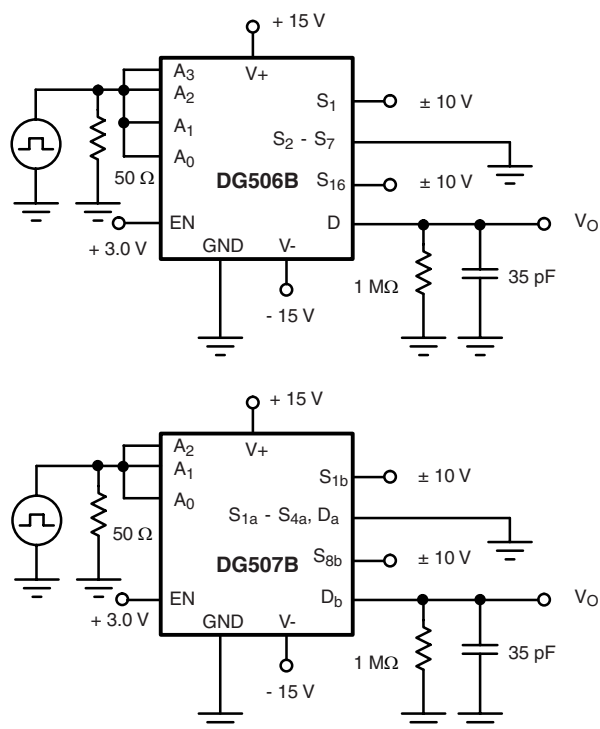
Capacitance vs. V_{ANALOG}



Capacitance vs. V_{ANALOG}



Capacitance vs. V_{ANALOG}

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

TEST CIRCUITS

Figure 2. Transition Time

TEST CIRCUITS

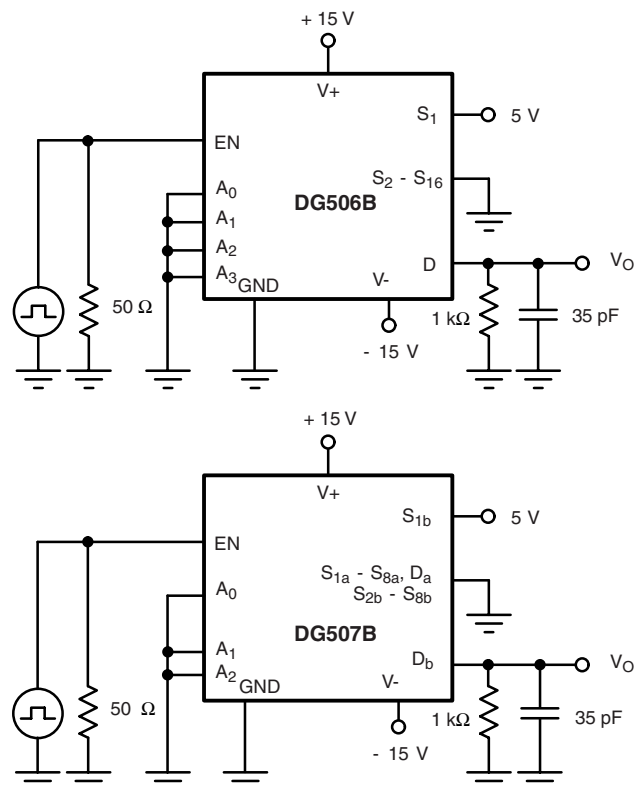


Figure 3. Enable Switching Time

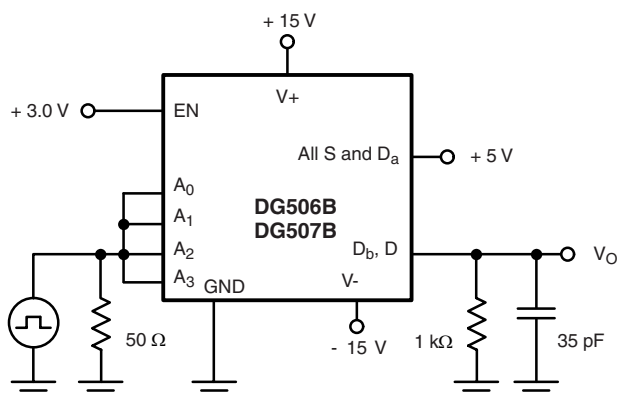
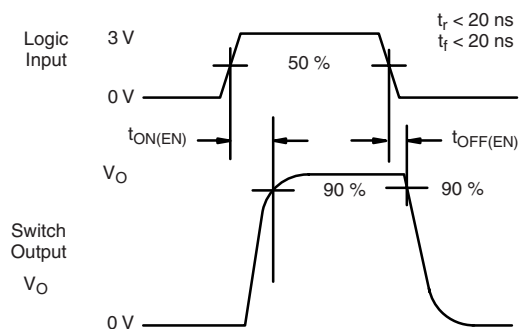
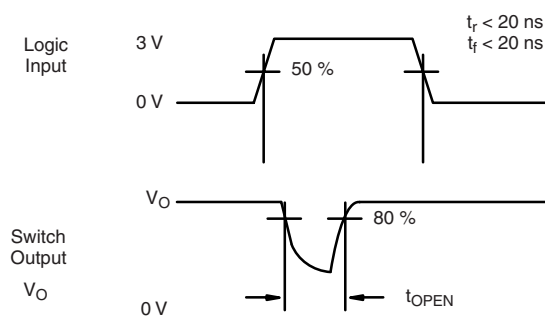
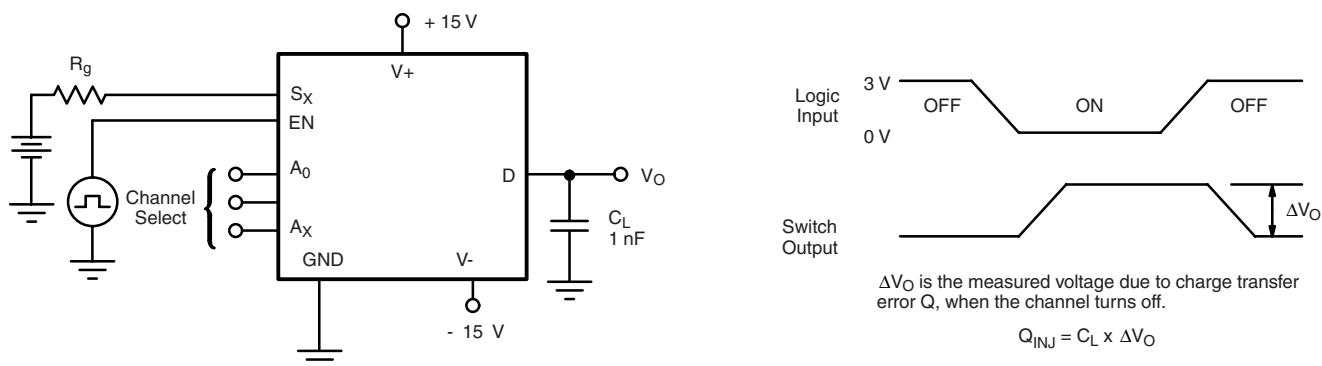
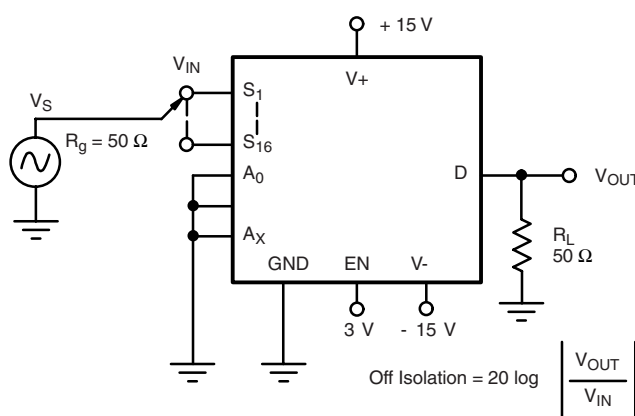
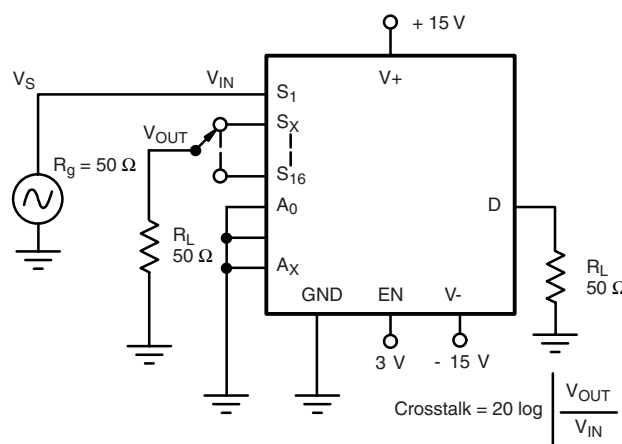
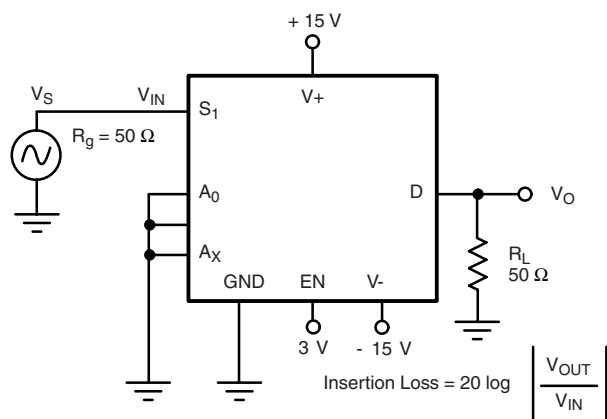
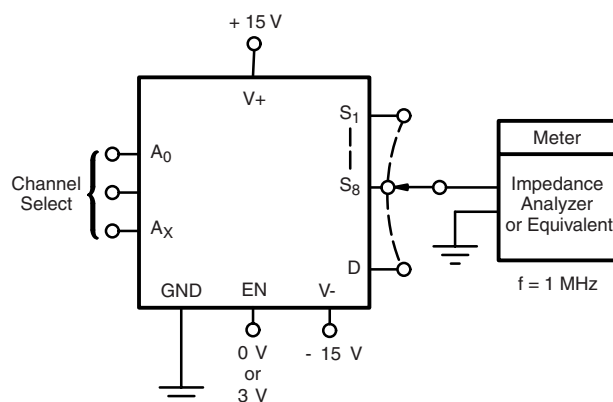


Figure 4. Break-Before-Make Interval

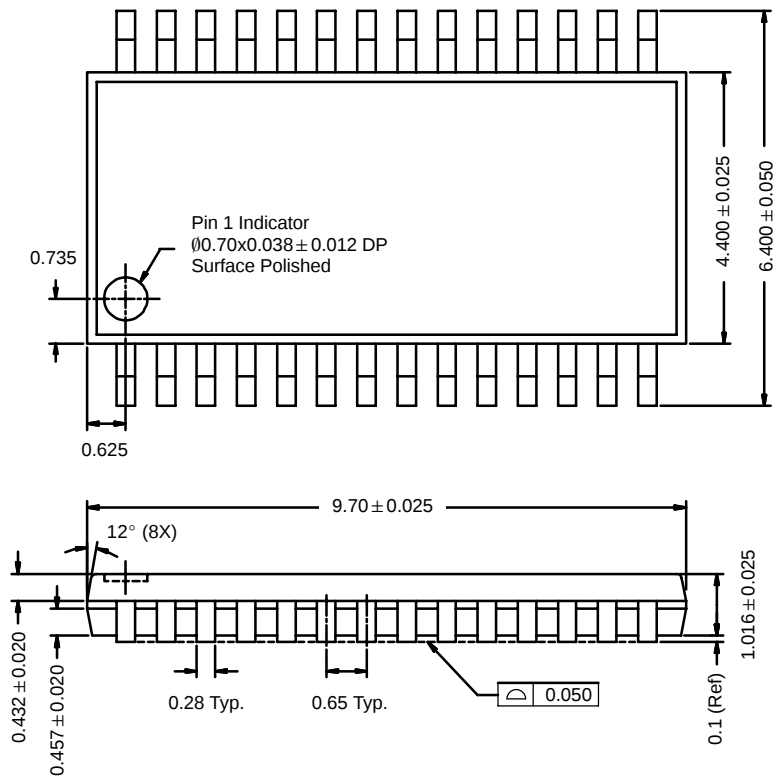


TEST CIRCUITS

Figure 5. Charge Injection

Figure 6. Off Isolation

Figure 7. Crosstalk

Figure 8. Insertion Loss

Figure 9. Source Drain Capacitance

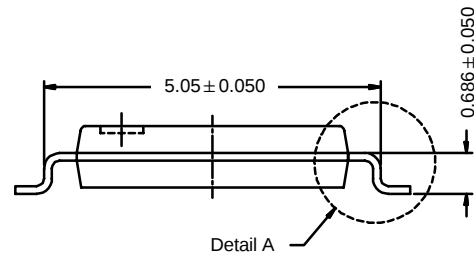
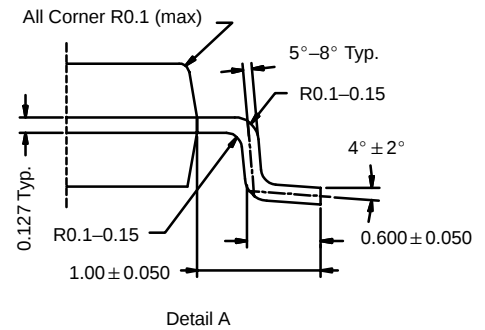
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?65150.



TSSOP: 28-LEAD



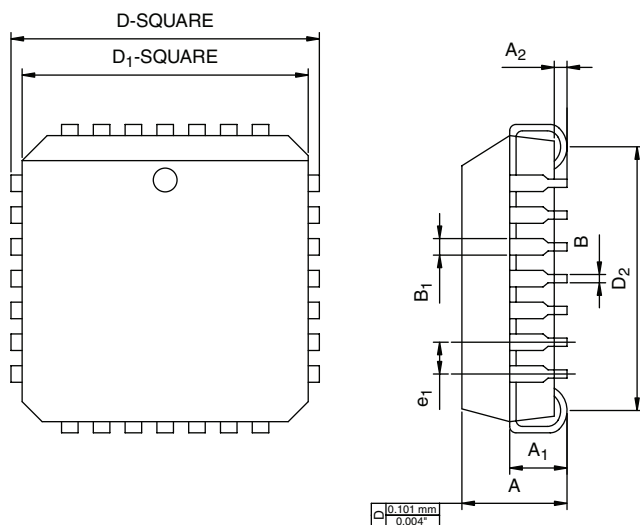
ECN: S-03946—Rev. C, 09-Jul-01
DWG: 5851



NOTES:

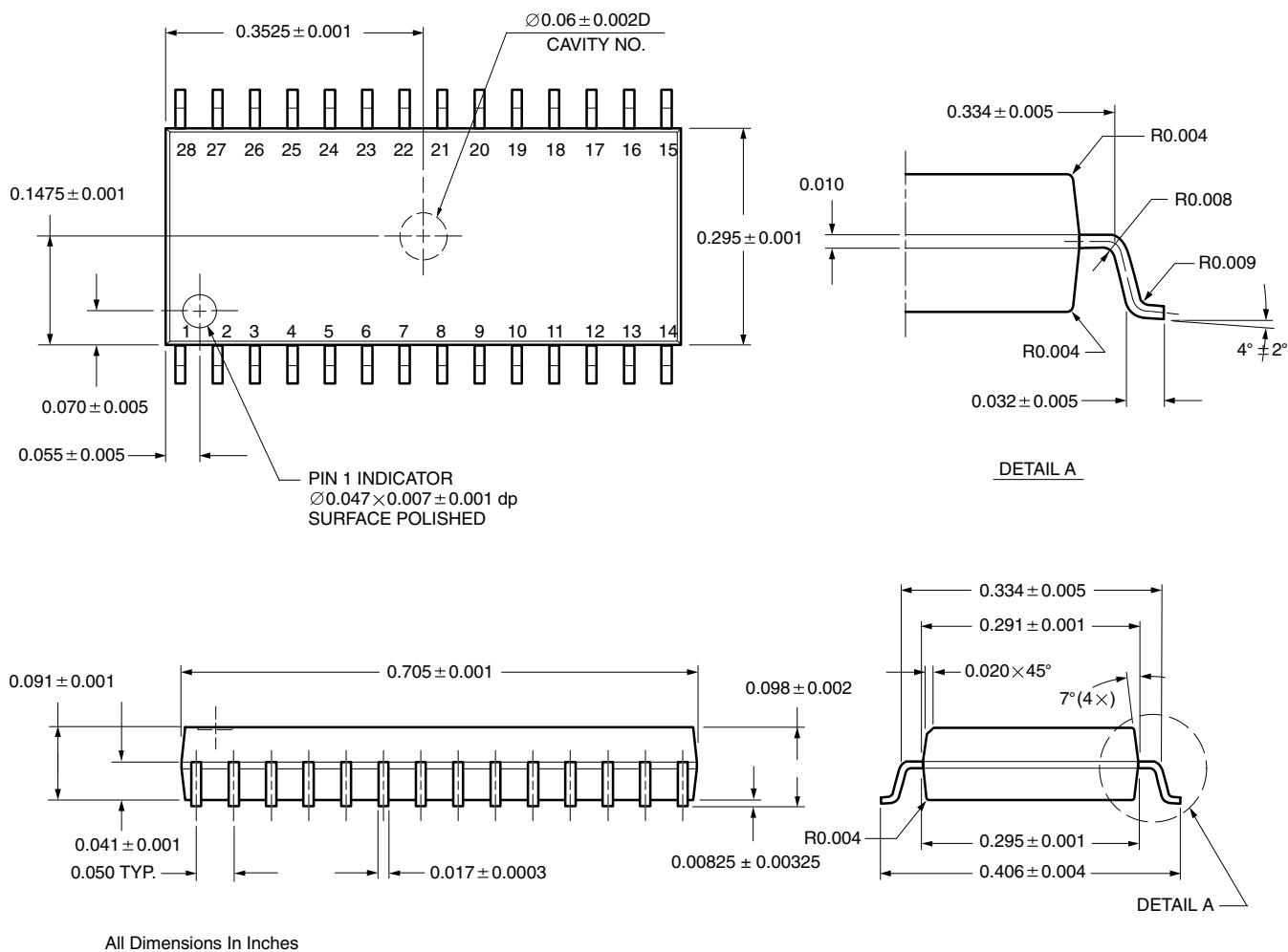
1. Package Surface: Shiny Finish (Ro 0.15 – 0.20).
2. Package Warpage: 0.012 (max).
3. Package Corner Radius: R0.1 mm (max).
4. Top to BTM Cavity Mismatch: 0.037 (max).
5. Tolerance: ± 0.050 unless otherwise specified.
6. End Flash Max: 0.1016 mm.

PLCC: 28-LEAD



DIM.	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	4.20	4.57	0.165	0.180
A ₁	2.29	3.04	0.090	0.120
A ₂	0.51	-	0.020	-
B	0.331	0.553	0.013	0.021
B ₁	0.661	0.812	0.026	0.032
D	12.32	12.57	0.485	0.495
D ₁	11.430	11.582	0.450	0.456
D ₂	9.91	10.92	0.390	0.430
e ₁	1.27 BSC		0.050 BSC	
ECN: T09-0766-Rev. D, 28-Sep-09 DWG: 5491				

SOIC (WIDE-BODY): 28-LEADS



ECN: E11-2209-Rev. D, 01-Aug-11
DWG: 5850



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- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
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Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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